

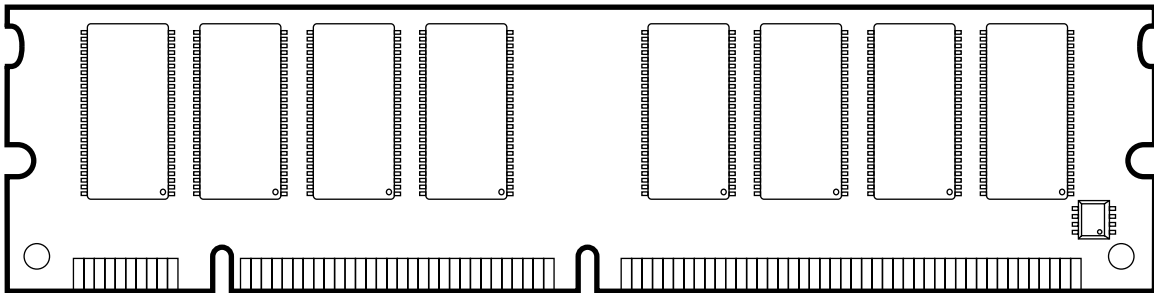
**3.3 VOLT 32M x 64 HIGH PERFORMANCE  
PC133 UNBUFFERED SDRAM MODULE****Features**

- 168 Pin Unbuffered 33,554,432 x 64 bit Organization SDRAM Modules
- Utilizes High Performance 32M x 8 SDRAM in TSOPII-54 Packages
- Fully PC Board Layout Compatible to INTEL'S Rev 1.0 Module Specification
- Single +3.3V ( $\pm 0.3V$ ) Power Supply
- Programmable  $\overline{CAS}$  Latency, Burst Length, and Wrap Sequence (Sequential & Interleave)
- Auto Refresh (CBR) and Self Refresh
- All Inputs, Outputs are LVTTTL Compatible
- 8192 Refresh Cycles every 64 ms
- Serial Presence Detect (SPD)

**Description**

The V436632S24V memory module is organized 33,554,432 x 64 bits in a 168 pin dual in line memory module (DIMM). The 32M x 64 unbuffered DIMM uses 8 Mosel-Vitelic 32M x 8 SDRAM. The x64 modules are ideal for use in high performance computer systems where increased memory density and fast access times are required.

| Part Number         | Speed Grade                | Configuration |
|---------------------|----------------------------|---------------|
| V436632S24VXTG-75PC | -75PC, CL=2,3<br>(133 MHz) | 32M x 64      |
| V436632S24VXTG-75   | -75, CL=3<br>(133 MHz)     | 32M x 64      |
| V436632S24VXTG-10PC | -10PC, CL=2,3<br>(100 MHz) | 32M x 64      |



**Pin Configurations (Front Side/Back Side)**

| Pin | Front           | Pin | Front            | Pin | Front | Pin | Back  | Pin | Back              | Pin | Back  |
|-----|-----------------|-----|------------------|-----|-------|-----|-------|-----|-------------------|-----|-------|
| 1   | VSS             | 29  | DQM1             | 57  | I/O19 | 85  | VSS   | 113 | DQM5              | 141 | I/O51 |
| 2   | I/O1            | 30  | $\overline{CS0}$ | 58  | I/O20 | 86  | I/O33 | 114 | $\overline{CS1}$  | 142 | I/O52 |
| 3   | I/O2            | 31  | DU               | 59  | VCC   | 87  | I/O34 | 115 | RAS               | 143 | VCC   |
| 4   | I/O3            | 32  | VSS              | 60  | I/O21 | 88  | I/O35 | 116 | VSS               | 144 | I/O53 |
| 5   | I/O4            | 33  | A0               | 61  | NC    | 89  | I/O36 | 117 | A1                | 145 | NC    |
| 6   | VCC             | 34  | A2               | 62  | DU    | 90  | VCC   | 118 | A3                | 146 | DU    |
| 7   | I/O5            | 35  | A4               | 63  | CKE1  | 91  | I/O37 | 119 | A5                | 147 | NC    |
| 8   | I/O6            | 36  | A6               | 64  | VSS   | 92  | I/O38 | 120 | A7                | 148 | VSS   |
| 9   | I/O7            | 37  | A8               | 65  | I/O22 | 93  | I/O39 | 121 | A9                | 149 | I/O54 |
| 10  | I/O8            | 38  | A10(AP)          | 66  | I/O23 | 94  | I/O40 | 122 | BA0               | 150 | I/O55 |
| 11  | I/O9            | 39  | BA1              | 67  | I/O24 | 95  | I/O41 | 123 | A11               | 151 | I/O56 |
| 12  | VSS             | 40  | VCC              | 68  | VSS   | 96  | VSS   | 124 | VCC               | 152 | VSS   |
| 13  | I/O10           | 41  | VCC              | 69  | I/O25 | 97  | I/O42 | 125 | CLK1              | 153 | I/O57 |
| 14  | I/O11           | 42  | CLK0             | 70  | I/O26 | 98  | I/O43 | 126 | A12               | 154 | I/O58 |
| 15  | I/O12           | 43  | VSS              | 71  | I/O27 | 99  | I/O44 | 127 | VSS               | 155 | I/O59 |
| 16  | I/O13           | 44  | DU               | 72  | I/O28 | 100 | I/O45 | 128 | $\overline{CKE0}$ | 156 | I/O60 |
| 17  | I/O14           | 45  | $\overline{CS2}$ | 73  | VCC   | 101 | I/O46 | 129 | $\overline{CS3}$  | 157 | VCC   |
| 18  | VCC             | 46  | DQM2             | 74  | I/O29 | 102 | VCC   | 130 | DQM6              | 158 | I/O61 |
| 19  | I/O15           | 47  | DQM3             | 75  | I/O30 | 103 | I/O47 | 131 | DQM7              | 159 | I/O62 |
| 20  | I/O16           | 48  | DU               | 76  | I/O31 | 104 | I/O48 | 132 | DU                | 160 | I/O63 |
| 21  | CBO*            | 49  | VCC              | 77  | I/O32 | 105 | CB4*  | 133 | VCC               | 161 | I/O64 |
| 22  | CB1*            | 50  | NC               | 78  | VSS   | 106 | CB5*  | 134 | NC                | 162 | VSS   |
| 23  | VSS             | 51  | NC               | 79  | CLK2  | 107 | VSS   | 135 | NC                | 163 | CLK3  |
| 24  | NC              | 52  | CB2*             | 80  | NC    | 108 | NC    | 136 | CB6*              | 164 | NC    |
| 25  | NC              | 53  | CB3*             | 81  | WP    | 109 | NC    | 137 | CB7*              | 165 | SA0   |
| 26  | VCC             | 54  | VSS              | 82  | SDA   | 110 | VCC   | 138 | VSS               | 166 | SA1   |
| 27  | $\overline{WE}$ | 55  | I/O17            | 83  | SCL   | 111 | CAS   | 139 | I/O49             | 167 | SA2   |
| 28  | DQM0            | 56  | I/O18            | 84  | VCC   | 112 | DQM4  | 140 | I/O50             | 168 | VCC   |

**Notes:**

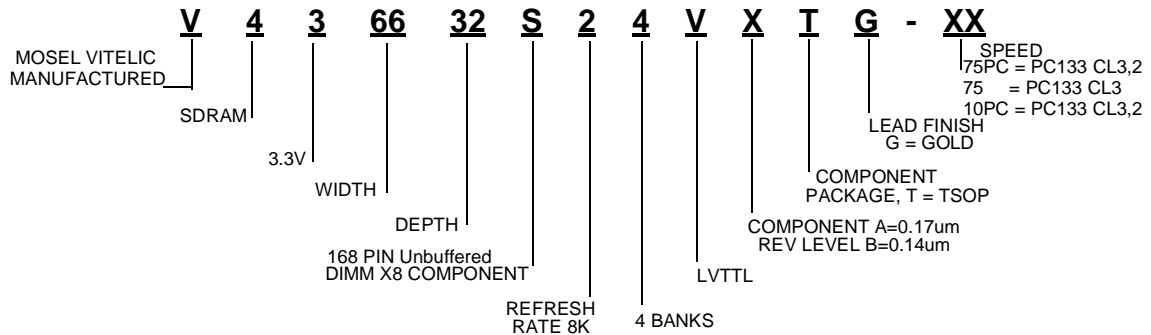
\* These pins are not used in this module.

**Pin Names**

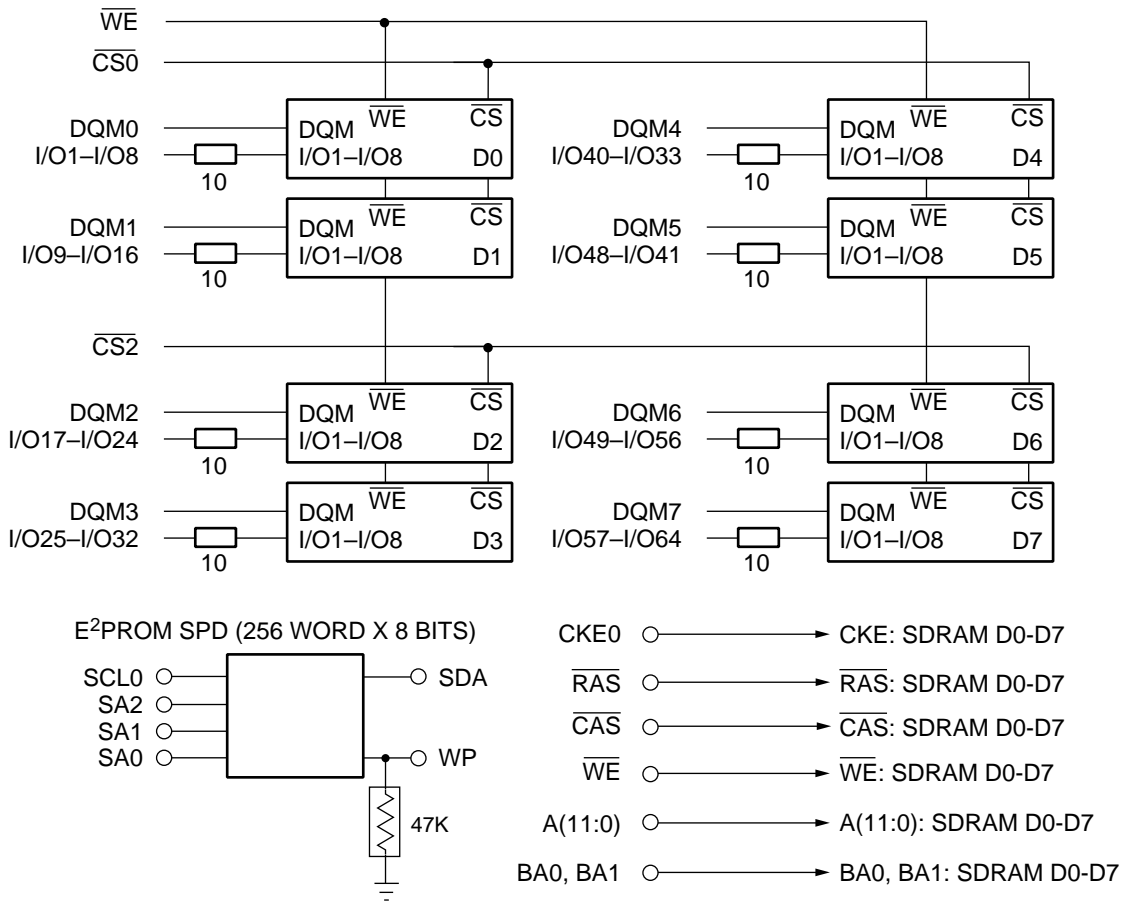
|                                       |                           |
|---------------------------------------|---------------------------|
| A0–A12                                | Address Inputs            |
| I/O1–I/O64                            | Data Inputs/Outputs       |
| $\overline{RAS}$                      | Row Address Strobe        |
| $\overline{CAS}$                      | Column Address Strobe     |
| $\overline{WE}$                       | Read/Write Input          |
| BA0, BA1                              | Bank Selects              |
| $\overline{CKE0}$ , $\overline{CKE1}$ | Clock Enable              |
| $\overline{CS0}$ – $\overline{CS3}$   | Chip Select               |
| CLK0–CLK3                             | Clock Input               |
| DQM0–DQM7                             | Data Mask                 |
| VCC                                   | Power (+3.3 Volts)        |
| VSS                                   | Ground                    |
| SCL                                   | Clock for Presence Detect |

|         |                                     |
|---------|-------------------------------------|
| SDA     | Serial Data OUT for Presence Detect |
| SA0–A2  | Serial Data IN for Presence Detect  |
| CB0–CB7 | Check Bits (x72 Organization)       |
| NC      | No Connection                       |
| DU      | Don't Use                           |

**Module Part Number Information**



**Block Diagram**



| CLOCK WIRING |                     |
|--------------|---------------------|
| CLOCK INPUT  | LOAD                |
| CLK0         | 5 SDRAM             |
| CLK1         | Termination         |
| CLK2         | 4 SDRAMs +3.3pF Cap |
| CLK3         | Termination         |

**Serial Presence Detect Information**

A serial presence detect storage device – E<sup>2</sup>PROM – is assembled onto the module. Information about the module configuration, speed, etc. is

written into the E<sup>2</sup>PROM device during module production using a serial presence detect protocol (I<sup>2</sup>C synchronous 2-wire bus)

**SPD-Table**

| Byte Number | Function Described  | SPD Entry Value          | Hex Value |     |       |
|-------------|---|--------------------------|-----------|-----|-------|
|             |   |                          | -75PC     | -75 | -10PC |
| 0           | Number of SPD bytes   | 128                      | 80        | 80  | 80    |
| 1           | Total bytes in Serial PD                                    | 256                      | 08        | 08  | 08    |
| 2           | Memory Type   | SDRAM                    | 04        | 04  | 04    |
| 3           | Number of Row Addresses (without BS bits)                   | 13                       | 0D        | 0D  | 0D    |
| 4           | Number of Column Addresses (for x8 SDRAM)                   | 10                       | 0A        | 0A  | 09    |
| 5           | Number of DIMM Banks  | 1                        | 01        | 01  | 01    |
| 6           | Module Data Width   | 64                       | 40        | 40  | 40    |
| 7           | Module Data Width (continued)                               | 0                        | 00        | 00  | 00    |
| 8           | Module Interface Levels                                     | LVTTL                    | 01        | 01  | 01    |
| 9           | SDRAM Cycle Time at CL=3                                    | 7.5 ns/10.0 ns           | 75        | 75  | A0    |
| 10          | SDRAM Access Time from Clock at CL=3                        | 5.4 ns/6.0 ns            | 54        | 54  | 60    |
| 11          | Dimm Config (Error Det/Corr.)                               | none                     | 00        | 00  | 00    |
| 12          | Refresh Rate/Type   | Self-Refresh, 7.8µs      | 82        | 82  | 82    |
| 13          | SDRAM width, Primary  | x8                       | 08        | 08  | 08    |
| 14          | Error Checking SDRAM Data Width                             | n/a / x8                 | 00        | 00  | 00    |
| 15          | Minimum Clock Delay from Back to Back Random Column Address | t <sub>ccd</sub> = 1 CLK | 01        | 01  | 01    |
| 16          | Burst Length Supported                                      | 1, 2, 4, 8               | 0F        | 0F  | 0F    |
| 17          | Number of SDRAM Banks                                       | 4                        | 04        | 04  | 04    |
| 18          | Supported CAS Latencies                                     | CL = 2, 3                | 06        | 06  | 06    |
| 19          | CS Latencies  | CS Latency = 0           | 01        | 01  | 01    |
| 20          | WE Latencies  | WL = 0                   | 01        | 01  | 01    |
| 21          | SDRAM DIMM Module Attributes                                | Non Buffered/Non Reg.    | 00        | 00  | 00    |
| 22          | SDRAM Device Attributes: General                            | Vcc tol ± 10%            | 0E        | 0E  | 0E    |
| 23          | Minimum Clock Cycle Time at CAS Latency = 2                 | 7.5 ns /10.0 ns          | 75        | A0  | A0    |
| 24          | Maximum Data Access Time from Clock for CL = 2              | 5.4 ns/ 6.0 ns           | 54        | 60  | 60    |
| 25          | Minimum Clock Cycle Time at CL = 1                          | Not Supported            | 00        | 00  | 00    |
| 26          | Maximum Data Access Time from Clock at CL = 1               | Not Supported            | 00        | 00  | 00    |
| 27          | Minimum Row Precharge Time                                  | 15 ns/20 ns              | 0F        | 14  | 14    |
| 28          | Minimum Row Active to Row Active Delay t <sub>RRD</sub>     | 14 ns/15 ns/16 ns        | 0E        | 0F  | 10    |
| 29          | Minimum RAS to CAS Delay t <sub>RCD</sub>                   | 15 ns/20 ns              | 0F        | 14  | 14    |

**SPD-Table**

| Byte Number | Function Described                           | SPD Entry Value | Hex Value |     |       |
|-------------|--|-----------------|-----------|-----|-------|
|             |  |                 | -75PC     | -75 | -10PC |
| 30          | Minimum RAS Pulse Width $t_{RAS}$            | 42 ns/45 ns     | 2A        | 2D  | 2D    |
| 31          | Module Bank Density (Per Bank)               | 256 MByte       | 40        | 40  | 40    |
| 32          | SDRAM Input Setup Time                       | 1.5 ns/2.0 ns   | 15        | 15  | 20    |
| 33          | SDRAM Input Hold Time                        | 0.8 ns/1.0 ns   | 08        | 08  | 10    |
| 34          | SDRAM Data Input Setup Time                  | 1.5 ns/2.0 ns   | 15        | 15  | 20    |
| 35          | SDRAM Data Input Hold Time                   | 0.8 ns/1.0 ns   | 08        | 08  | 10    |
| 36-61       | Superset Information (May be used in Future) |                 | 00        | 00  | 00    |
| 62          | SPD Revision                                 | Revision 2/1.2  | 02        | 02  | 12    |
| 63          | Checksum for Bytes 0 - 62                    |                 | FD        | 42  | B0    |
| 64          | Manufacturer's JEDEC ID Code                 | Mosel Vitelic   | 40        | 40  | 40    |
| 65-71       | Manufacturer's JEDEC ID Code (cont.)         |                 | 00        | 00  | 00    |
| 72          | Manufacturing Location                       |                 |           |     |       |
| 73-90       | Module Part Number (ASCII)                   | V436632S24V     |           |     |       |
| 91-92       | PCB Identification Code                      |                 |           |     |       |
| 93          | Assembly Manufacturing Date (Year)           |                 |           |     |       |
| 94          | Assembly Manufacturing Date (Week)           |                 |           |     |       |
| 95-98       | Assembly Serial Number                       |                 |           |     |       |
| 99-125      | Reserved                                     |                 | 00        | 00  | 00    |
| 126         | Intel Specification for Frequency            |                 | 64        | 64  | 64    |
| 127         | Supported frequency                          |                 |           |     |       |
| 128+        | Unused Storage Location                      |                 | 00        | 00  | 00    |

**DC Characteristics**

$T_A = 0^{\circ}C$  to  $70^{\circ}C$ ;  $V_{SS} = 0 V$ ;  $V_{DD}, V_{DDQ} = 3.3V \pm 0.3V$

| Symbol     | Parameter   | Limit Values |              | Unit    |
|------------|---|--------------|--------------|---------|
|            |   | Min.         | Max.         |         |
| $V_{IH}$   | Input High Voltage  | 2.0          | $V_{CC}+0.3$ | V       |
| $V_{IL}$   | Input Low Voltage   | -0.5         | 0.8          | V       |
| $V_{OH}$   | Output High Voltage ( $I_{OUT} = -4.0$ mA)  | 2.4          | —            | V       |
| $V_{OL}$   | Output Low Voltage ( $I_{OUT} = 4.0$ mA)  | —            | 0.4          | V       |
| $I_{I(L)}$ | Input Leakage Current, any input<br>( $0 V < V_{IN} < 3.6 V$ , all other inputs = 0V) | -10          | 10           | $\mu A$ |
| $I_{O(L)}$ | Output leakage current<br>(DQ is disabled, $0V < V_{OUT} < V_{CC}$ )                  | -10          | 10           | $\mu A$ |

**Capacitance**
 $T_A = 0^\circ\text{C to } 70^\circ\text{C}; V_{DD} = 3.3\text{V} \pm 0.3\text{V}, f = 1\text{ MHz}$ 

| Symbol           | Parameter  | Limit Values | Unit |
|------------------|--|--------------|------|
| C <sub>I1</sub>  | Input Capacitance (A0 to A11, $\overline{\text{RAS}}$ , $\overline{\text{CAS}}$ , $\overline{\text{WE}}$ ) | 85           | pF   |
| C <sub>I2</sub>  | Input Capacitance ( $\overline{\text{CS0}}$ - $\overline{\text{CS3}}$ )                                    | 30           | pF   |
| C <sub>ICL</sub> | Input Capacitance (CLK0-CLK3)  | 22           | pF   |
| C <sub>I3</sub>  | Input Capacitance (CKE0, CKE1)   | 50           | pF   |
| C <sub>I4</sub>  | Input Capacitance (DQM0-DQM7)  | 20           | pF   |
| C <sub>IO</sub>  | Input/Output Capacitance (I/O1-I/O64)  | 20           | pF   |
| C <sub>SC</sub>  | Input Capacitance (SCL, SA0-2)   | 8            | pF   |
| C <sub>SD</sub>  | Input/Output Capacitance   | 18           | pF   |

**Absolute Maximum Ratings**

| Parameter   | Max.       | Units |
|---|------------|-------|
| Voltage on VDD Supply Relative to V <sub>SS</sub> | -1 to 4.6  | V     |
| Voltage on Input Relative to V <sub>SS</sub>      | -1 to 4.6  | V     |
| Operating Temperature                             | 0 to +70   | °C    |
| Storage Temperature                               | -55 to 125 | °C    |
| Power Dissipation                                 | 6.5        | W     |

**MOSEL VITELIC**  
**Standby and Refresh Currents<sup>1</sup>**

V436632S24V

T<sub>A</sub> = 0°C to 70°C, V<sub>CC</sub> = 3.3V ± 0.3V

| Symbol            | Parameter   | Test Conditions   | -75PC/75  | -10PC | Unit | Note                   |     |
|-------------------|---|---|-----------|-------|------|------------------------|-----|
| I <sub>CC1</sub>  | Operating Current                                 | Burst length = 4, CL = 3<br>t <sub>RC</sub> > = t <sub>RC</sub> (min),<br>t <sub>CK</sub> > = t <sub>CK</sub> (min), IO = 0 mA<br>2 Bank Interleave Operation | 1840      | 1680  | mA   | 1,2                    |     |
| I <sub>CC2P</sub> | Precharged Standby Current in PowerDown Mode      | CKE< = V <sub>IL</sub> (max), t <sub>CK</sub> > = t <sub>CK</sub> (min)   | 16        | 16    | mA   |                        |     |
| I <sub>CC2N</sub> | Precharged Standby Current in Non-Power Down Mode | CKE> = V <sub>IH</sub> (min), t <sub>CK</sub> > = t <sub>CK</sub> (min), Input changed once in 3 cycles   | 360       | 280   | mA   | $\overline{CS}$ = High |     |
| I <sub>CC3P</sub> | Active Standby Current in Power Down Mode         | CKE< = V <sub>IL</sub> (max), t <sub>CK</sub> > = t <sub>CK</sub> (min)   | 80        | 80    | mA   |                        |     |
| I <sub>CC3N</sub> | Active Standby Current in Non-Power Down Mode     | CKE> = V <sub>IH</sub> (min), t <sub>CK</sub> > = t <sub>CK</sub> (min), Input changed one time   | 400       | 360   | mA   | $\overline{CS}$ = High |     |
| I <sub>CC4</sub>  | Burst Operating Current                           | t <sub>RC</sub> = Infinite, CL = 3,<br>t <sub>CK</sub> > = t <sub>CK</sub> (min), IO = 0 mA<br>2 Banks Activated  | 1360      | 960   | mA   | 1, 2                   |     |
| I <sub>CC5</sub>  | Auto Refresh Current                              | t <sub>RC</sub> >= t <sub>RC</sub> (min)  | 1920      | 1760  | mA   | 1,2                    |     |
| I <sub>CC6</sub>  | Self Refresh Current                              | CKE = <0,2 V  | Standard  | 24    | 24   | mA                     | 1,2 |
|                   |   |   | L-version | 12    | 12   |                        |     |

**AC Characteristics** <sup>3,4</sup>

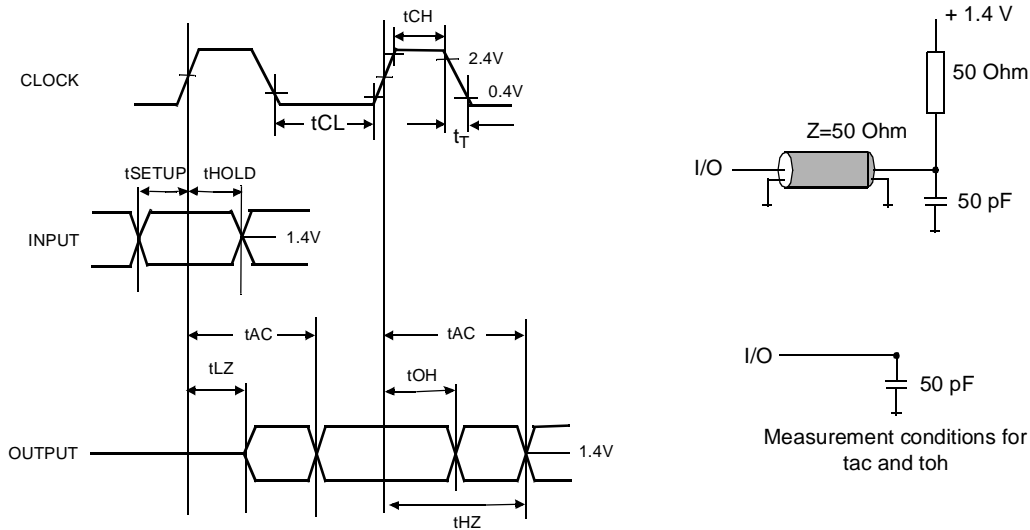
$T_A = 0^\circ$  to  $70^\circ\text{C}$ ;  $V_{SS} = 0\text{V}$ ;  $V_{CC} = 3.3\text{V} \pm 0.3\text{V}$ ,  $t_T = 1\text{ ns}$

| #                             | Symbol     | Parameter   | Limit Values |            |           |            |          |            | Unit       | Note |
|-------------------------------|------------|---|--------------|------------|-----------|------------|----------|------------|------------|------|
|                               |            |   | -75PC        |            | -75       |            | -10PC    |            |            |      |
|                               |            |   | MIN          | MAX        | MIN       | MAX        | MIN      | MAX        |            |      |
| <b>Clock and Clock Enable</b> |            |   |              |            |           |            |          |            |            |      |
| 1                             | $t_{CK}$   | Clock Cycle Time<br>$\overline{\text{CAS}}$ Latency = 3<br>$\overline{\text{CAS}}$ Latency = 2  | 7.5<br>7.5   |            | 7.5<br>10 |            | 10<br>10 |            | ns<br>ns   |      |
| 2                             | $f_{CK}$   | System frequency<br>$\overline{\text{CAS}}$ Latency = 3<br>$\overline{\text{CAS}}$ Latency = 2  | –<br>–       | 133<br>133 | –<br>–    | 133<br>100 | –<br>–   | 100<br>100 | MHz<br>MHz |      |
| 3                             | $t_{AC}$   | Clock Access Time<br>$\overline{\text{CAS}}$ Latency = 3<br>$\overline{\text{CAS}}$ Latency = 2 | –<br>–       | 5.4<br>6   | –<br>–    | 5.4<br>6   | –<br>–   | 6<br>6     | ns<br>ns   | 4,5  |
| 4                             | $t_{CH}$   | Clock High Pulse Width  | 2.5          | –          | 2.5       | –          | 3        | –          | ns         | 6    |
| 5                             | $t_{CL}$   | Clock Low Pulse Width   | 2.5          | –          | 2.5       | –          | 3        | –          | ns         | 6    |
| 6                             | $t_{CS}$   | Input Setup time  | 1.5          | –          | 1.5       | –          | 2        | –          | ns         | 7    |
| 7                             | $t_{CH}$   | Input Hold Time   | 0.8          | –          | 0.8       | –          | 1        | –          | ns         | 7    |
| 8                             | $t_{CKSP}$ | CKE Setup Time (Power down mode)  | 2            | –          | 2         | –          | 2        | –          | ns         | 8    |
| 9                             | $t_{CKSR}$ | CKE Setup Time (Self Refresh Exit)  | 8            | –          | 8         | –          | 8        | –          | ns         | 9    |
| 10                            | $t_T$      | Transition time (rise and fall)   | 1            | –          | 1         | –          | 1        | –          | ns         |      |
| <b>Common Parameters</b>      |            |   |              |            |           |            |          |            |            |      |
| 11                            | $t_{RCD}$  | $\overline{\text{RAS}}$ to $\overline{\text{CAS}}$ delay  | 15           | –          | 20        | –          | 20       | –          | ns         |      |
| 12                            | $t_{RC}$   | Cycle Time  | 70           | 120k       | 70        | 120k       | 70       | 120k       | ns         |      |
| 13                            | $t_{RAS}$  | Active Command Period   | 42           | –          | 45        | –          | 45       | –          | ns         |      |
| 14                            | $t_{RP}$   | Precharge Time  | 15           | –          | 20        | –          | 20       | –          | ns         |      |
| 15                            | $t_{RRD}$  | Bank to Bank Delay Time   | 14           | –          | 15        | –          | 20       | –          | ns         |      |
| 16                            | $t_{CCD}$  | $\overline{\text{CAS}}$ to $\overline{\text{CAS}}$ delay time (same bank)                       | 1            | –          | 1         | –          | 1        | –          | CLK        |      |
| <b>Refresh Cycle</b>          |            |   |              |            |           |            |          |            |            |      |
| 17                            | $t_{SREX}$ | Self Refresh Exit Time  | 10           | –          | 10        | –          | 10       | –          | ns         | 9    |
| 18                            | $t_{REF}$  | Refresh Period (8192 cycles)  | 64           | –          | 64        | –          | 64       | –          | ms         | 8    |
| <b>Read Cycle</b>             |            |   |              |            |           |            |          |            |            |      |
| 19                            | $t_{OH}$   | Data Out Hold Time  | 3            | –          | 3         | –          | 3        | –          | ns         | 4    |
| 20                            | $t_{LZ}$   | Data Out to Low Impedance Time  | 0            | –          | 0         | –          | 0        | –          | ns         |      |
| 21                            | $t_{HZ}$   | Data Out to High Impedance Time   | 3            | 7.5        | 3         | 7.5        | 3        | 8          | ns         | 10   |
| 22                            | $t_{DQZ}$  | DQM Data Out Disable Latency  | 2            | –          | 2         | –          | 2        | –          | CLK        |      |
| <b>Write Cycle</b>            |            |   |              |            |           |            |          |            |            |      |
| 23                            | $t_{DPL}$  | Data input to Precharge (write recovery)  | 2            | –          | 2         | –          | 1        | –          | CLK        |      |
| 24                            | $t_{DAL}$  | Data In to Active/refresh   | 5            | –          | 5         | –          | 5        | –          | CLK        | 11   |
| 25                            | $t_{DQW}$  | DQM Write Mask Latency  | 0            | –          | 0         | –          | 0        | –          | CLK        |      |



**Notes:**

1. The specified values are valid when addresses are changed no more than once during  $t_{CK}(\text{min.})$  and when No Operation commands are registered on every rising clock edge during  $t_{RC}(\text{min.})$ . Values are shown per module bank.
2. The specified values are valid when data inputs (DQ's) are stable during  $t_{RC}(\text{min.})$ .
3. All AC characteristics are shown for device level.  
An initial pause of 100  $\mu\text{s}$  is required after power-up, then a Precharge All Banks command must be given followed by 8 Auto Refresh (CBR) cycles before the Mode Register Set Operation can begin.
4. AC timing tests have  $V_{IL} = 0.4\text{V}$  and  $V_{IH} = 2.4\text{V}$  with the timing referenced to the 1.4V crossover point. The transition time is measured between  $V_{IH}$  and  $V_{IL}$ . All AC measurements assume  $t_T = 1 \text{ ns}$  with the AC output load circuit shown. Specific  $t_{ac}$  and  $t_{oh}$  parameters are measured with a 50 pF only, without any resistive termination and with a input signal of 1V / ns edge rate between 0.8V and 2.0V.

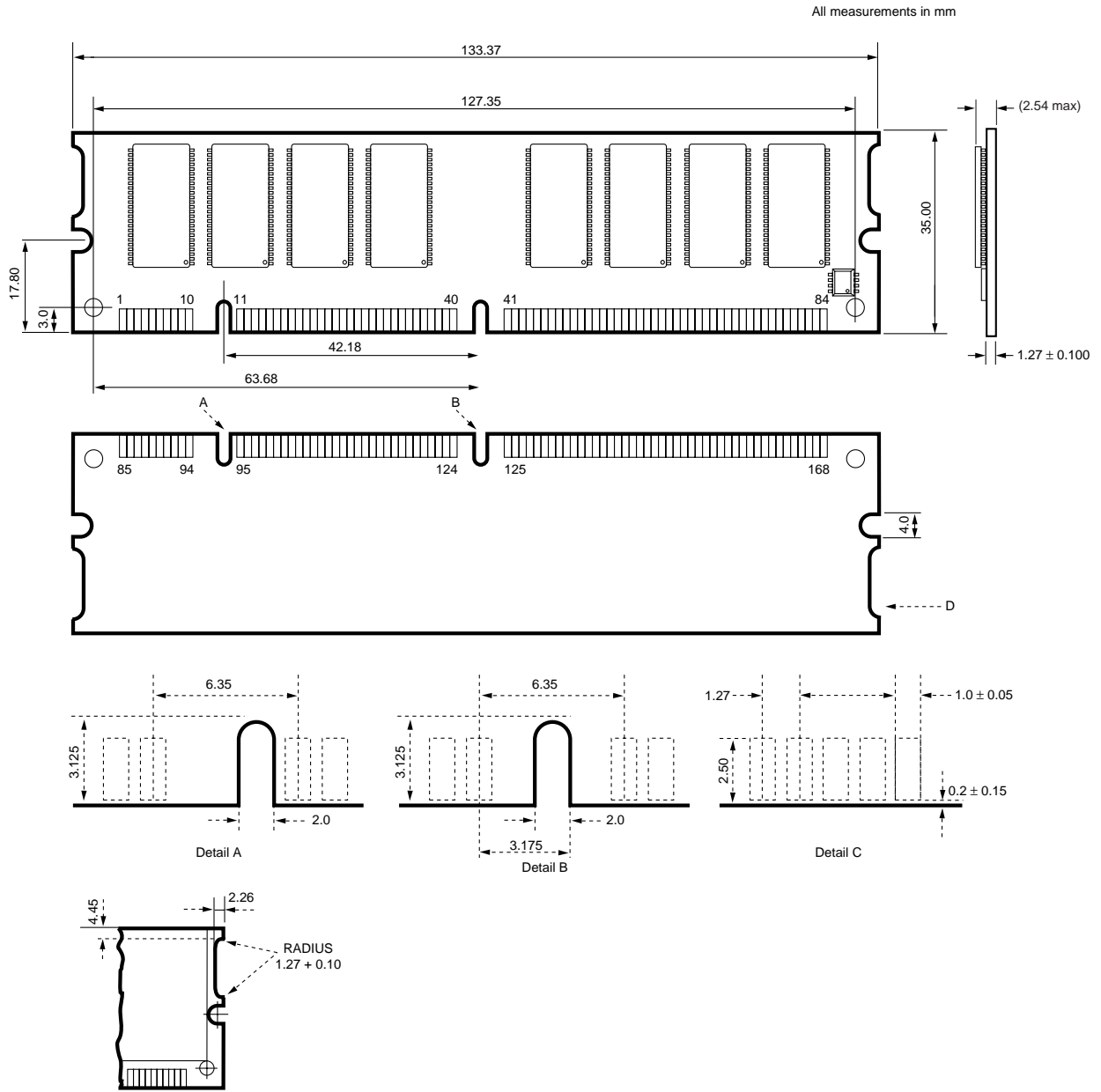


5. If clock rising time is longer than 1 ns, a time  $(t_T/2 - 0.5)$  ns has to be added to this parameter.
6. Rated at 1.5V
7. If  $t_T$  is longer than 1 ns, a time  $(t_T - 1)$  ns has to be added to this parameter.
8. Any time that the refresh Period has been exceeded, a minimum of two Auto (CBR) Refresh commands must be given to "wake-up" the device.
9. Self Refresh Exit is a synchronous operation and begins on the 2nd positive clock edge after CKE returns high. Self Refresh Exit is not complete until a time period equal to  $t_{RC}$  is satisfied once the Self Refresh Exit command is registered.
10. Referenced to the time which the output achieves the open circuit condition, not to output voltage levels.
11.  $t_{DAL}$  is equivalent to  $t_{DPL} + t_{RP}$ .

**Package Diagram**

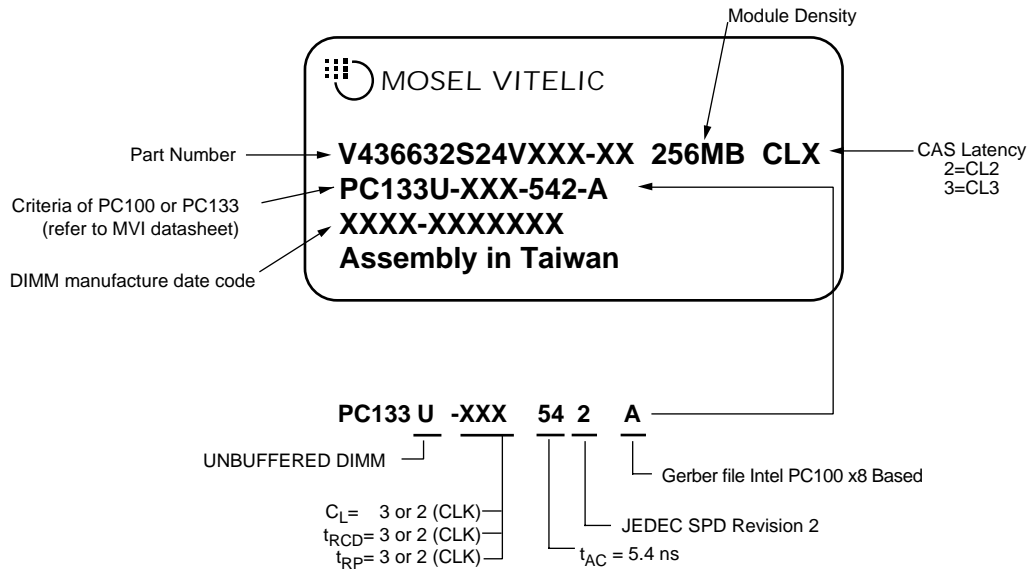
**L-DIM-168-30**

**SDRAM DIMM Module Package**



Tolerances: ± (0.13) unless otherwise specified.

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